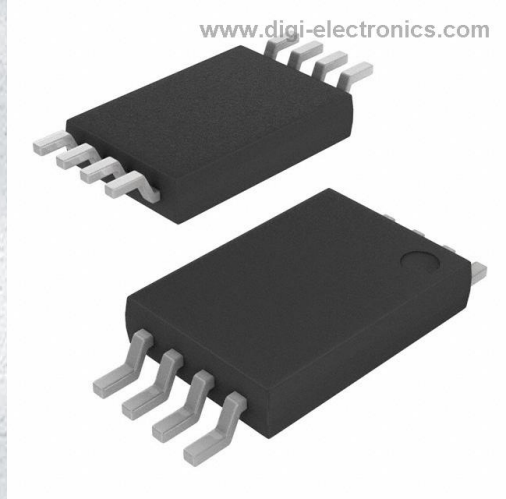
DMN2016UTS-13 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number	DMN2016UTS-13-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	DMN2016UTS-13
Description	MOSFET 2N-CH 20V 8.58A 8TSSOP
Detailed Description	Mosfet Array 20V 8.58A 880mW Surface Mount 8-TSSOP

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
DMN2016UTS-13	Diodes Incorporated
Series:	Product Status:
-	Active
Technology:	Configuration:
MOSFET (Metal Oxide)	2 N-Channel (Dual) Common Drain
FET Feature:	Drain to Source Voltage (Vdss):
Logic Level Gate	20V
Current - Continuous Drain (Id) @ 25°C:	Rds On (Max) @ Id, Vgs:
8.58A	14.5mOhm @ 9.4A, 4.5V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
1V @ 250µA	16.5nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds:	Power - Max:
1495pF @ 10V	880mW
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
8-TSSOP (0.173", 4.40mm Width)	8-TSSOP
Base Product Number:	
DMN2016	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.21.0095	

NEW PRODUCT

DMN2016UTS

DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Please click here to visit our online spice models database.

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- **Lead Free By Design/RoHS Compliant (Note 1)**
- **ESD Protected Up To 2KV**
- **"Green" Device (Note 2)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

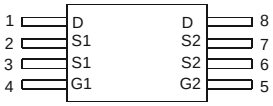
- Case: TSSOP-8L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.039 grams (approximate)

ESD PROTECTED TO 2kV

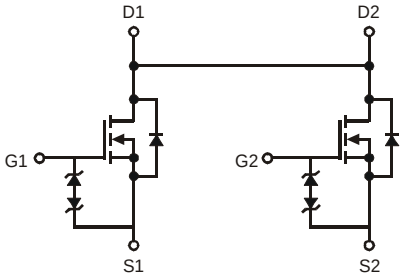
TOP VIEW

BOTTOM VIEW

TSSOP-8L



Top View
Pin Configuration



Internal Schematic

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V_{DSS}	20	V
Gate-Source Voltage			V_{GSS}	±8	V
Continuous Drain Current (Note 3)	Steady State	T_A = 25°C T_A = 85°C	I_D	8.58 5.73	A
Pulsed Drain Current (Note 4)			I_{DM}	36	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3)	P_D	0.88	W
Thermal Resistance, Junction to Ambient @T_A = 25°C (Note 3)	$R_{\theta JA}$	141.57	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Notes:
1. No purposefully added lead.
2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
3. Device mounted on FR-4 PCB, with minimum recommended pad layout.
4. Repetitive rating, pulse width limited by junction temperature.

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Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)						
Drain-Source Breakdown Voltage	BV_{DSS}	20	-	-	V	V_{GS} = 0V, I_D = 250µA
Zero Gate Voltage Drain Current T_J = 25°C	I_{DSS}	-	-	1.0	µA	V_{DS} = 20V, V_{GS} = 0V
Gate-Source Leakage	I_{GSS}	-	-	±10	µA	V_{GS} = ±8V, V_{DS} = 0V
ON CHARACTERISTICS (Note 5)						
Gate Threshold Voltage	$V_{GS(th)}$	0.4	0.72	1.0	V	V_{DS} = V_{GS}, I_D = 250µA
Static Drain-Source On-Resistance	$R_{DS\ (ON)}$	-	11 13	14.5 16.5	mΩ	V_{GS} = 4.5V, I_D = 9.4A V_{GS} = 2.5V, I_D = 8.3A
Forward Transfer Admittance	$\|Y_{fs}\|$	-	19	-	S	V_{DS} = 5V, I_D = 9.4A
Diode Forward Voltage	V_{SD}	-	0.65	1.2	V	V_{GS} = 0V, I_S = 1.3A
DYNAMIC CHARACTERISTICS (Note 6)						
Input Capacitance	C_{iss}	-	1495	-	pF	V_{DS} = 10V, V_{GS} = 0V, f = 1.0MHz
Output Capacitance	C_{oss}	-	161	-	pF	
Reverse Transfer Capacitance	C_{rss}	-	152	-	pF	
Gate Resistance	R_g	-	1.42	-	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1MHz
Total Gate Charge	Q_g	-	16.5	-	nC	V_{GS} = 4.5V, V_{DS} = 10V, I_D = 9.4A
Gate-Source Charge	Q_{gs}	-	2.5	-	nC	
Gate-Drain Charge	Q_{gd}	-	3.2	-	nC	
Turn-On Delay Time	$t_{D(on)}$	-	10.39	-	ns	V_{DD} = 10V, V_{GS} = 4.5V, R_{GEN} = 6Ω, I_D = 1A, R_1 = 10Ω
Turn-On Rise Time	t_r	-	11.66	-	ns	
Turn-Off Delay Time	$t_{D(off)}$	-	59.38	-	ns	
Turn-Off Fall Time	t_f	-	16.27	-	ns	

Notes: 5. Short duration pulse test used to minimize self-heating effect.
6. Guaranteed by design. Not subject to production testing.

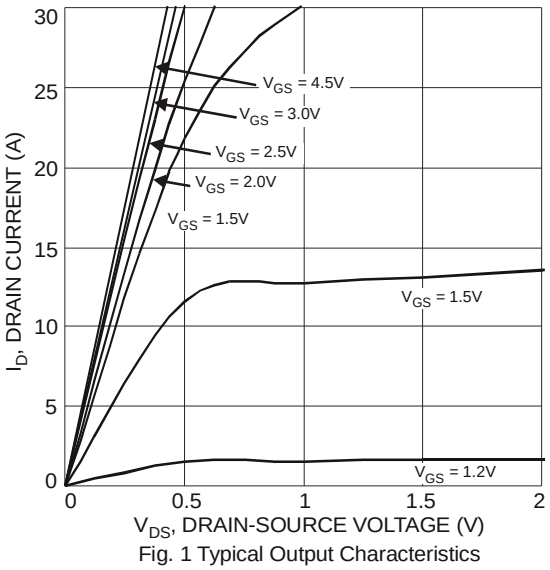

Fig. 1 Typical Output Characteristics

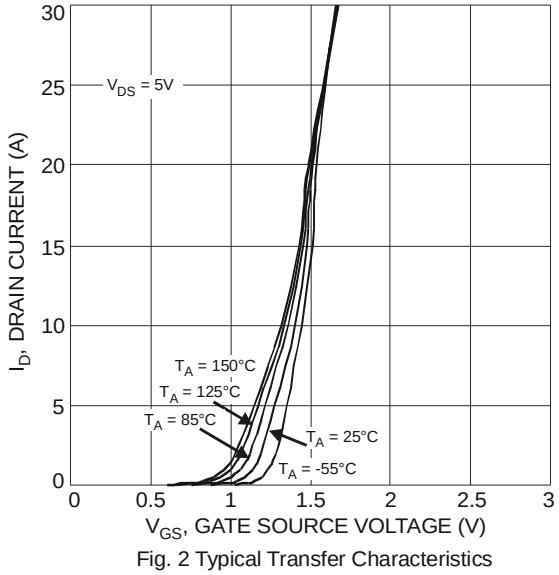

Fig. 2 Typical Transfer Characteristics

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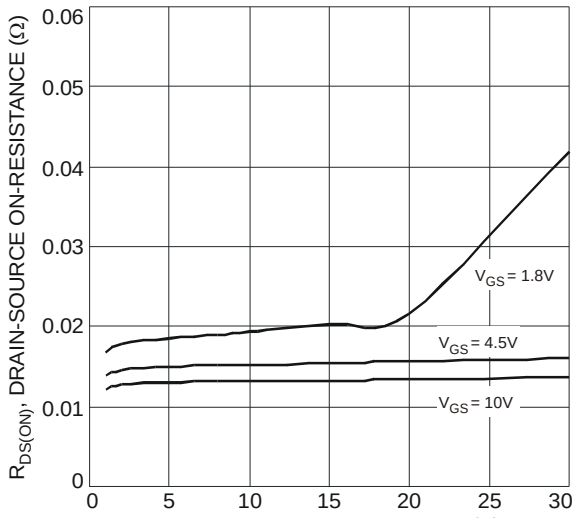

Fig. 3 Typical On-Resistance
vs. Drain Current and Gate Voltage

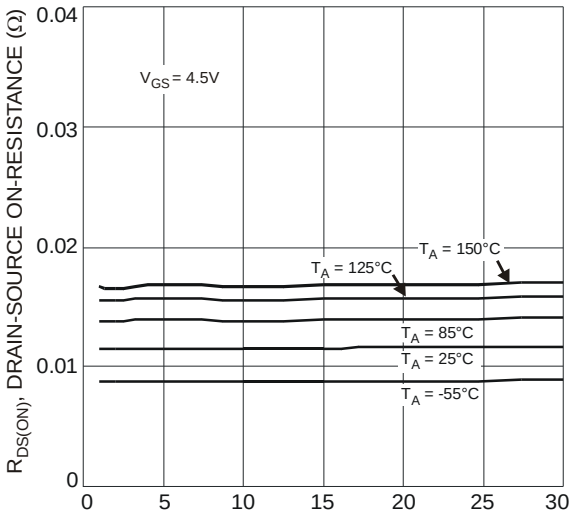

Fig. 4 Typical Drain-Source On-Resistance
vs. Drain Current and Temperature

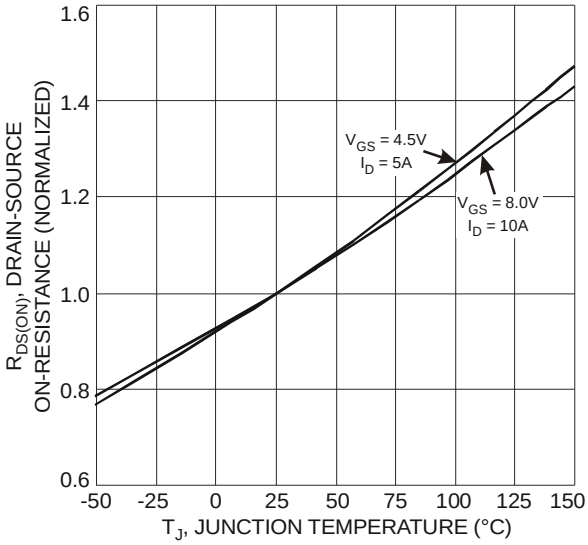

Fig. 5 On-Resistance Variation with Temperature

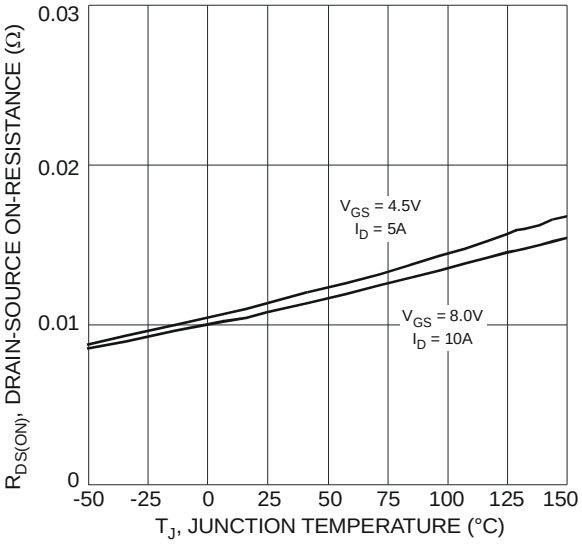

Fig. 6 On-Resistance Variation with Temperature

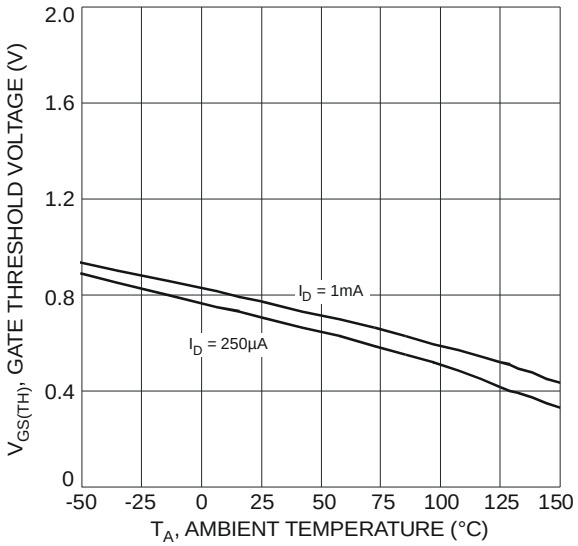

Fig. 7 Gate Threshold Variation vs. Ambient Temperature

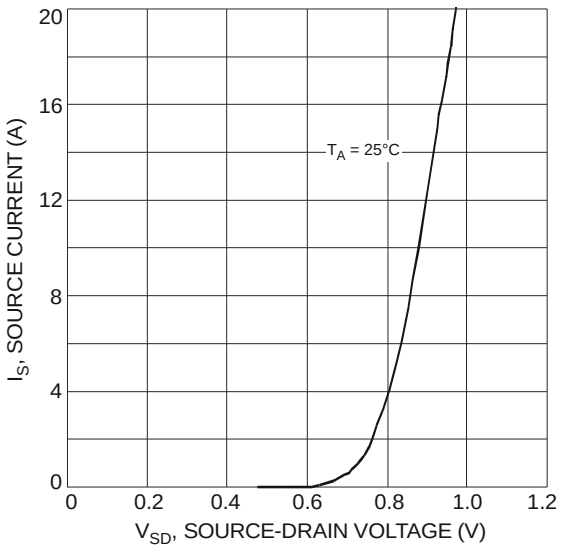

Fig. 8 Diode Forward Voltage vs. Current

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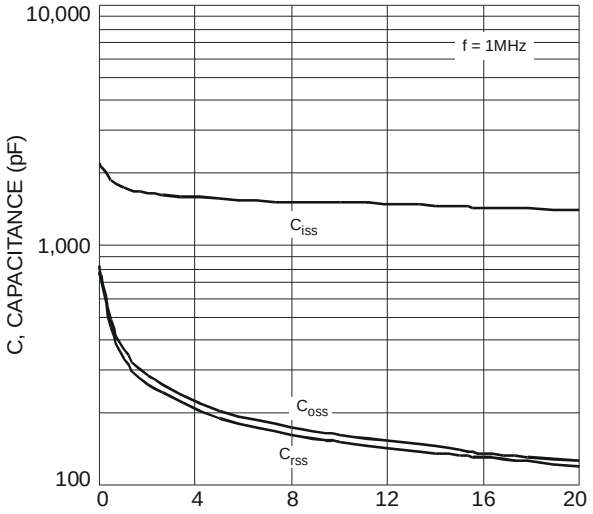


Fig. 9 Typical Capacitance

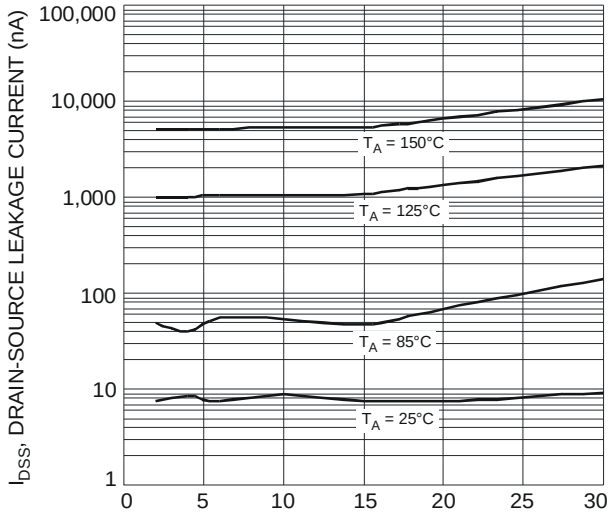


Fig. 10 Typical Drain-Source Leakage Current vs. Drain-Source Voltage

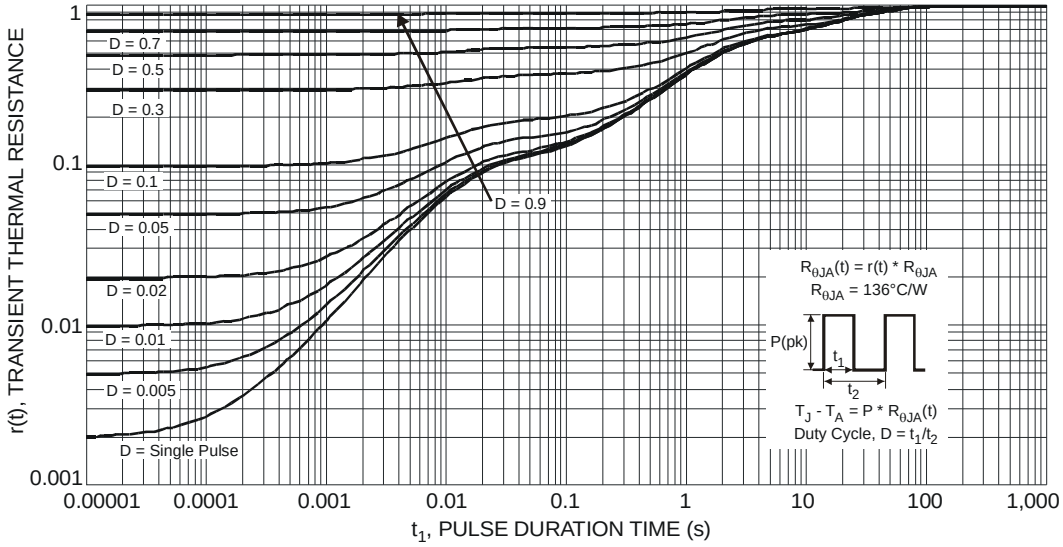


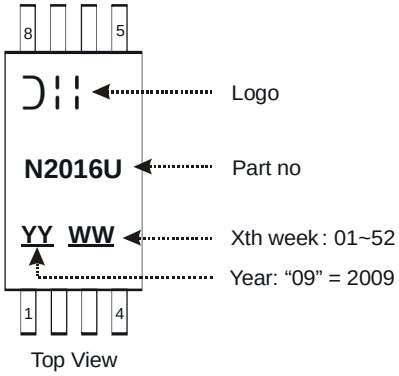
Fig. 11 Transient Thermal Response

Ordering Information (Note 7)

Part Number	Case	Packaging
DMN2016UTS-13	TSSOP-8L	2500 / Tape & Reel

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



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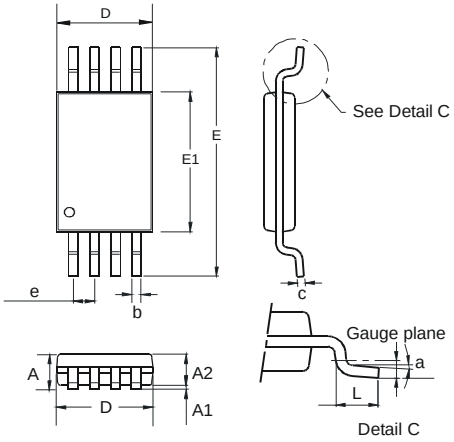
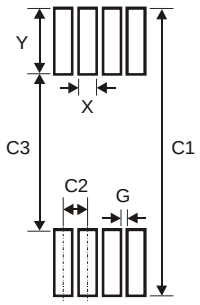
Package Outline Dimensions



TSSOP-8L			
Dim	**Min**	**Max**	**Typ**
a	0.09	–	–
A	–	1.20	–
A1	0.05	0.15	–
A2	0.825	1.025	0.925
b	0.19	0.30	–
c	0.09	0.20	–
D	2.90	3.10	3.025
e	–	–	0.65
E	–	–	6.40
E1	4.30	4.50	4.425
L	0.45	0.75	0.60
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
X	0.45
Y	1.78
C1	7.72
C2	0.65
C3	4.16
G	0.20

NEW PRODUCT

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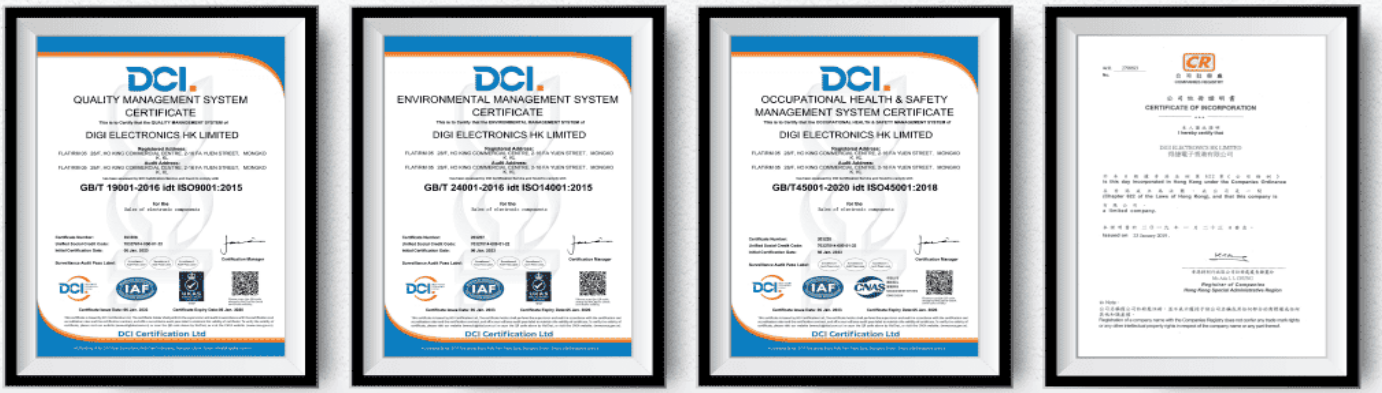

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